## NSN 5962-01-101-3756

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Body	Length:
	inches
	Width:
	inches
	Height:
	inches
Maxin	num Power Dissipation Rating:
	milliwatts
Opera	ting Tempurature Range:
+0.0/+	70.0 degrees celsius
Stora	ge Tempurature Range:
-55.0/	+150.0 degrees celsius
Featu	res Provided:
Herme	stically sealed and monolithic and positive outputs and high speed and w/enable
Inclos	ure Material:
Ceran	nic and glass
Inclos	sure Configuration:
Dual-i	n-line
Outpu	It Logic Form:
N-type	e metal oxide-semiconductor logic
Input	Circuit Pattern:
14 inp	ut
Termi	nal Surface Treatment:
Solde	
Volta	ge Rating And Type Per Characteristic:
20.0 v	olts power source
Time	Rating Per Chacteristic:
200.0	) nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level
output	
Memo	ry Device Type:
Rom	
Memo	ory Capacity:
Unkno	wn
Termi	nal Type And Quantity:
18 pri	nted circuit
Shelf	Life:
N/a	
Unit C	of Measure:
Demil	itarization:
Yes -	demil/mli
Fiig:	
A458a	0